

## THE SPECIFICATION OF AlGaAs IR LED CHIP "IR4C"

### 1. DESCRIPTION

This is a AlGaAs red LED chip. It is N-side up. The peak wavelength is 810 nm (Typ.).

### 2. ELECTRO - OPTICAL CHARACTERISTICS (Ta=25deg. C)

CONDITION	MIN.	TYP.	MAX.	UNIT
Forward Voltage ( $V_F$ ) IF=20mA		1.65		V
Reverse Voltage ( $V_R$ ) IR=10uA	5			V
Radiated Power <sup>1)</sup> ( $P_o$ ) IF=20mA	1.0			mW
Peak Wavelength ( $\lambda_P$ ) IF=20mA	800	810	820	nm
Spectral Radiation Bandwidth ( $\Delta\lambda$ ) IF=20mA		30		nm

1) LED chip is mounted on TO-18 gold header without resin coated.

### 3. ABSOLUTE MAXIMUM RATINGS

Continuous Maximum Forward Current	: 100 mA(DC)
Reverse Voltage	: 5 V(IR=10uA)
Storage Temperature	
while on mylar membrane	: 0 to 40 deg. C
after removal from mylar membrane	: -40 to 100 deg. C

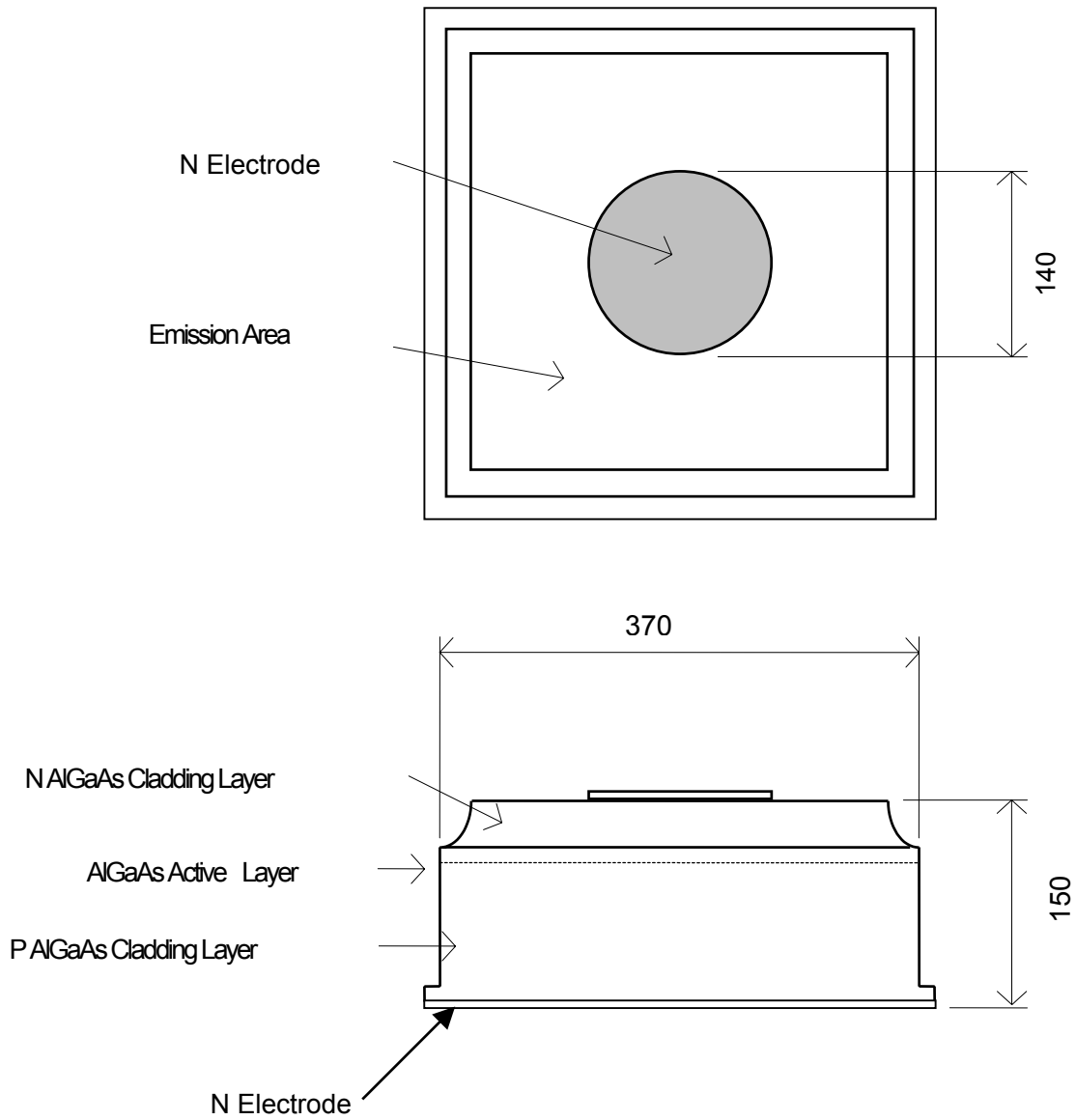
### 4. PHYSICAL CHARACTERISTICS AND STRUCTURE

- 1) Material : AlGaAs
- 2) Structure : Double Hetero Structure
- 3) Junction Size : 0.370mmX0.370mm
- 4) Thickness : 0.150mm
- 5) Bond Pad Size : 0.140mm diameter
- 6) Anode Metallization : Gold Alloy
- 7) Cathode Metallization: Gold Alloy

Physical Dimensions

Model IR4C

Unit: um



Remark: This specification is for reference purpose only, and subject to change without prior notice.  
Approved specification shall be obtained for the regular purchase.